

Modeling, Extraction and Verification of VCSEL Model for IBIS AMI

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Outline

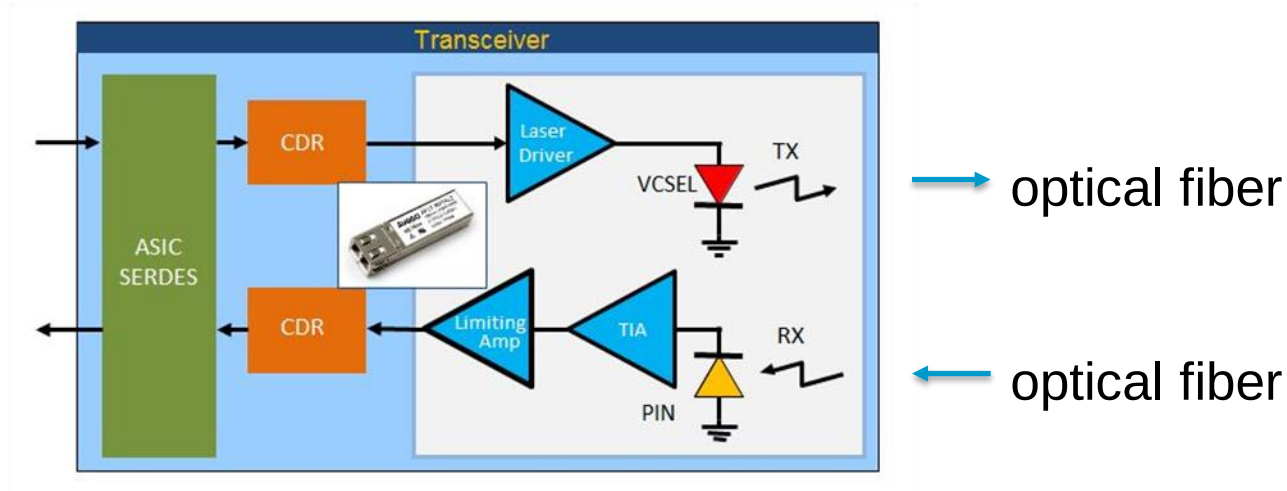
- Introduction
 - Optical Link Simulation
 - VCSEL(Vertical Cavity Surface Emitting Laser) simulation under IBIS-AMI
- VCSEL Modeling and Extraction
 - Thermal based modeling
 - Curve fitting algorithm
- VCSEL Verification
 - Test case including VCSEL device
 - The comparison between simulation and measured data



Introduction

Optical Link System and Simulation(cont.)

- Optical Link Simulation



Inside SerDes Tx & Rx

- Equalization (FFE, CTLE & DFE)
- Clock-data recovery (CDR)

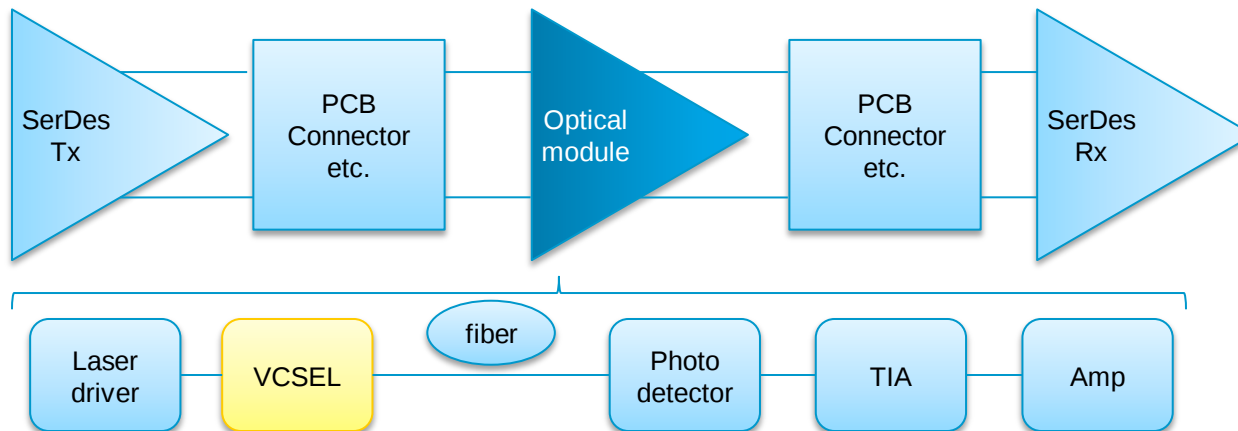
Inside optical module

- Input voltage signal drives VCSEL to emit photons
- Photons propagate along optical fiber
- Photons are converted into photocurrent in PIN
- TIA converts current into output voltage

Introduction

Optical Link System and Simulation(cont.)

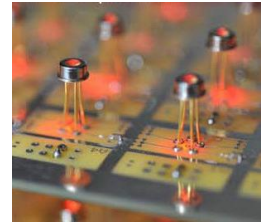
- Extending AMI to Optical Channel
 - Treat the entire optical module as a mid-channel repeater
 - Encapsulate all optical behaviors inside the optical model
 - Extend AMI simulation to include repeater



Introduction

VCSEL Basic

- VCSEL(Vertical Cavity Emitting Laser)
 - Characteristics
 - High Data Rate, up to 40GHz(state of art)
 - Low power cost(input ~ mA, output ~ mW)
 - Single-longitudinal-mode operation
 - Suitability for monolithic 2-D integration
 - Application
 - Very short range data transmission
 - Board to board data transmission



Introduction

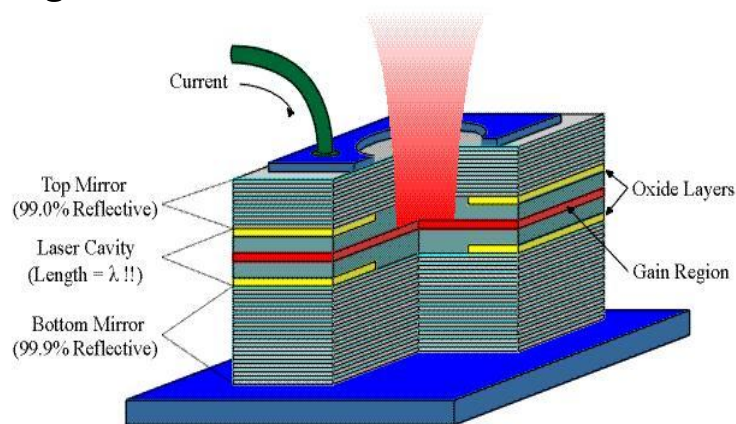
VCSEL Basic

- VCSEL modeling
 - 3-D modeling and simulation
 - From the principle of laser point of view
 - Accurate but too complicated
 - SPICE simulation
 - As VCSEL is an optical device, SPICE model may not be the initial design, a new SPICE schematic is needed
 - Hard to communicate due to IP issue
- IBIS-AMI(Algorithmic Modeling Interface)
 - Focusing on performance only
 - Treat the VCSEL as an algorithm unit

VCSEL Modeling and Extraction

VCSEL Modeling

- Modeling Principle
 - VCSEL's performance vs. Thermal behavior
 - Data flow based
 - The relationship between input current(I) and output power(P_o) under the effect of temperature(T)
 - Peripheral simulation
 - Working schematic



VCSEL Modeling and Extraction

VCSEL Modeling

- Rate-Equation-Based Thermal VCSEL Model
- Transient Analysis

$P_o = kS$	$\frac{dS}{dt} = -\frac{S}{\tau_p} + \frac{\beta N}{\tau_n} + \frac{G_o(N - N_o)S}{1 + \varepsilon S}$ $\frac{dN}{dt} = \frac{\eta_i(I - I_{off}(T))}{q} - \frac{N}{\tau_n} - \frac{G_o(N - N_o)S}{1 + \varepsilon S}$ Rate Equation	$I_{off}(T) = a_0 + a_1T + a_2T^2 + a_3T^3 + a_4T^4$	$T = T_o + (IV - P_o)R_{th} - \tau_{th} \frac{dT}{dt}$ $V = \begin{cases} (b_0 + b_1T + b_2T^2)(c_0 + c_1I + c_2I^2) \\ (c_0 + c_1I + c_2I^2 + c_3I^3 + c_4I^4 + c_5I^5 + c_6I^6) \\ AI + B \ln(1 + \frac{I}{C}) \end{cases}$
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- Stationary Analysis

$P_o = \eta(I - I_{tho} - I_{off}(T))$	$I_{off}(T) = a_0 + a_1T + a_2T^2 + a_3T^3 + a_4T^4$	$T = T_o + (IV - P_o)R_{th}$ $V = \begin{cases} (b_0 + b_1T + b_2T^2)(c_0 + c_1I + c_2I^2) \\ (c_0 + c_1I + c_2I^2 + c_3I^3 + c_4I^4 + c_5I^5 + c_6I^6) \\ AI + B \ln(1 + \frac{I}{C}) \end{cases}$
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VCSEL Modeling and Extraction

VCSEL Extraction

- Extraction Basics
 - VCSEL's performance $\leftrightarrow$ Parameter values in rate equations
 - Measured curves
 - $LI \sim Po(I; T)$
 - Measured stationary, shows the relationship between input current and the output power under different ambient temperature
 - $VI \sim V(I; T)$
 - Measured stationary, shows the relationship between input current and the voltage for connection, also with effect of ambient temperature
 - Frequency response $\sim H(w)$
 - Measured stationary, shows the frequency response, reveals the signal transmission characteristics

VCSEL Modeling and Extraction

VCSEL Extraction

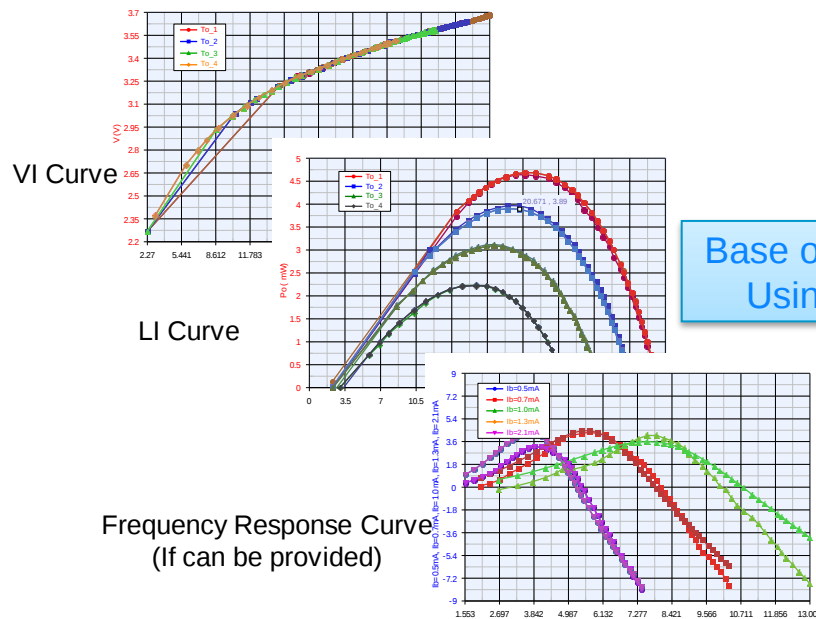
- Extraction Method
 - Curve Fitting Algorithm
 - LS curve fitting
 - Just solve the matrix equations
 - Suitable for simple relationship equations, such as the polynomial
 - Accurate and less time cost
 - Minimal gradient curve fitting
 - Try to find the certain set of values which can generate the smallest error
 - Suitable for more complex equations, especially with iterations
 - Need some pre-knowledge of the range of the parameters
 - More time cost for accuracy



VCSEL Modeling and Extraction

VCSEL Extraction

- Schematic



Base on Rate Equations
Using Curve Fitting

```
_DeviceName_ : C:\Users\zhaokvua\Desktop\Device1.dat  
_Eta_        : 0.399619  
_Rth_        : 2.80217  
_Itho_       : 0.306942  
_Ai_         : [1.35978 0.439447 0.788546 0.353605 0.00607852 ]  
_VIModel_    : 1  
_VIArray_    : [3.38977 34.0683 -1311.94 62247.5 -2.72387e+006  
_EtaI_       : 0.623601  
_Beta_       : 1.00003e-007  
_Taon_       : 5.29655e-009  
_k_          : 4.16084e-008  
_Go_         : 85398.5  
_No_         : 1.84006e+006  
_Taop_       : 2.47013e-012  
_epsilon_    : 1.72085e-017
```



VCSEL Verification

- VCSEL Simulation
 - Parameter values in rate equations ↔ VCSEL's performance
 - Schematic

$$\frac{dN}{dt} = \frac{\eta_i(I - I_{off}(T))}{q} - \frac{N}{\tau_n} - \frac{G_o(N - N_o)S}{1 + \epsilon S}$$

$$\frac{dS}{dt} = -\frac{S}{\tau_p} + \frac{\beta N}{\tau_n} + \frac{G_o(N - N_o)S}{1 + \epsilon S}$$

$$I_{off}(T) = \sum_i a_i T^i$$

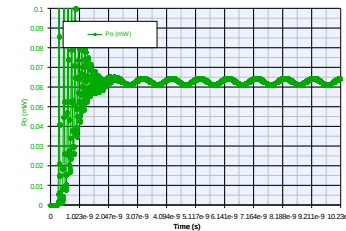
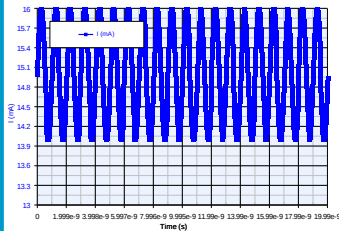
$$V = f(I, T)$$

$$T = T_o + (IV - P_o)R_{th} - \tau_{th} \frac{dT}{dt}$$

$$P_o = kS$$

```

DeviceName_ : C:\Users\zhaokyua\Desktop\Device1.dat
Eta_        : 0.399619
Rth_        : 2.80217
Itho_       : 0.306942
Ai_         : [1.35978 0.439447 0.788546 0.353605 0.00607852 ]
VIModel_    : 1
VIArray_    : [3.38977 34.0683 -1311.94 62247.5 -2.72387e+006
Etal_       : 0.623601
Beta_       : 1.00003e-007
Taon_       : 5.29655e-009
k_          : 4.16084e-008
Go_         : 85398.5
No_         : 1.84006e+006
Taop_       : 2.47013e-012
epsilon_    : 1.72085e-017
    
```



VCSEL Verification

- Case 1 ~ device verification

- 863-nm bottom-emitting VCSEL, 16-mm diameter

- Extraction

- Curves fitting result

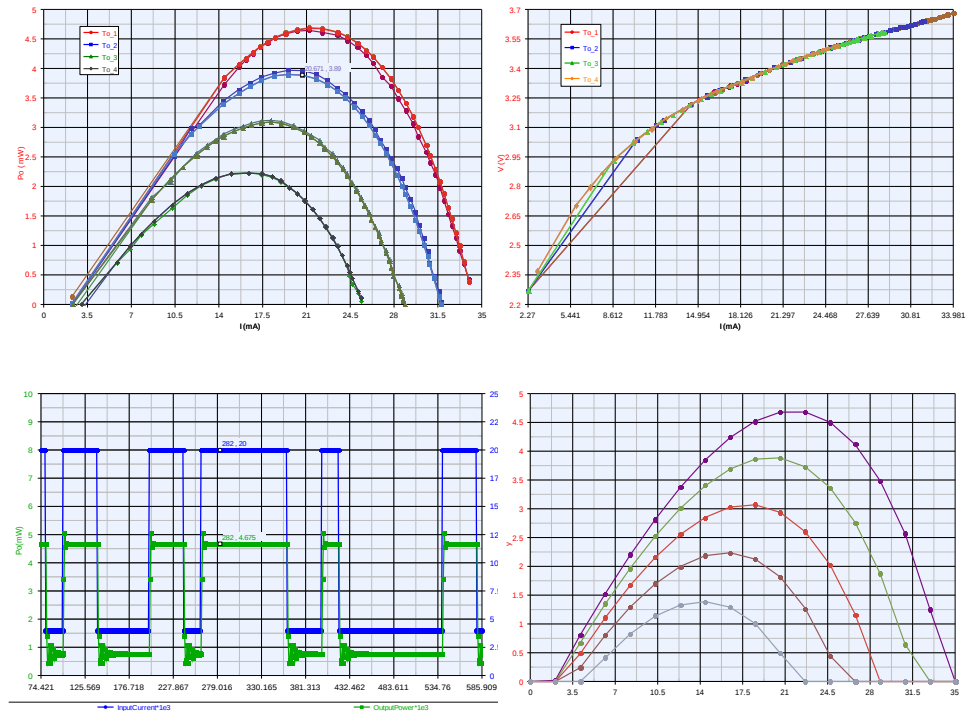
- LI and VI curve

- Behavior mode is generated with file format

- Simulation

- Po(I) under different To

- Response for large signal



VCSEL Verification

- Case 2 ~ device verification
 - 3.1 μ m diameter thin-oxide-aperture VCSEL
 - Extraction Result
 - Curves fitting result
 - LI(Fig 1)
 - VI(Fig 2)
 - Freq. response(Fig3)
 - Simulation
 - Po(I) simulation (Fig4)
 - Frequency response(Fig5)
 - Response for large signal(Fig6)

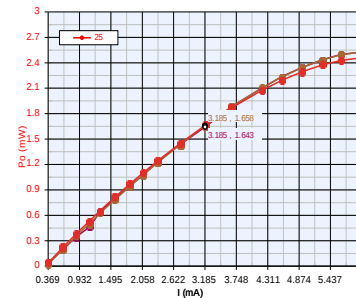


Fig 1

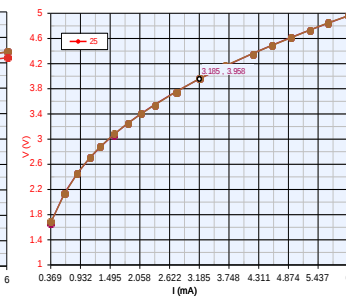


Fig 2

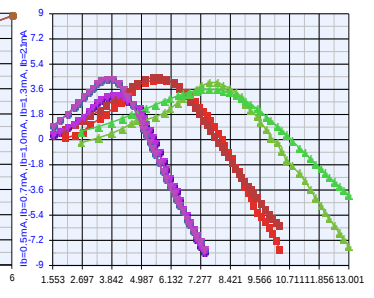


Fig 3

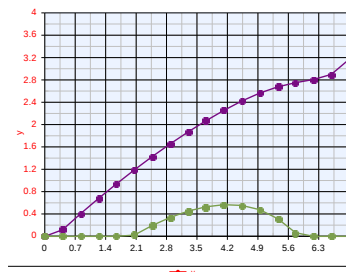


Fig 4

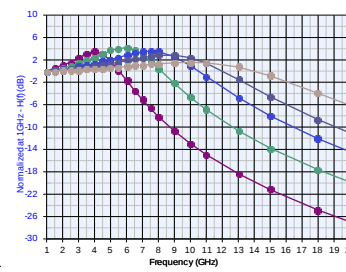


Fig 5

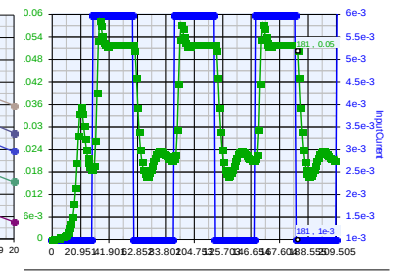
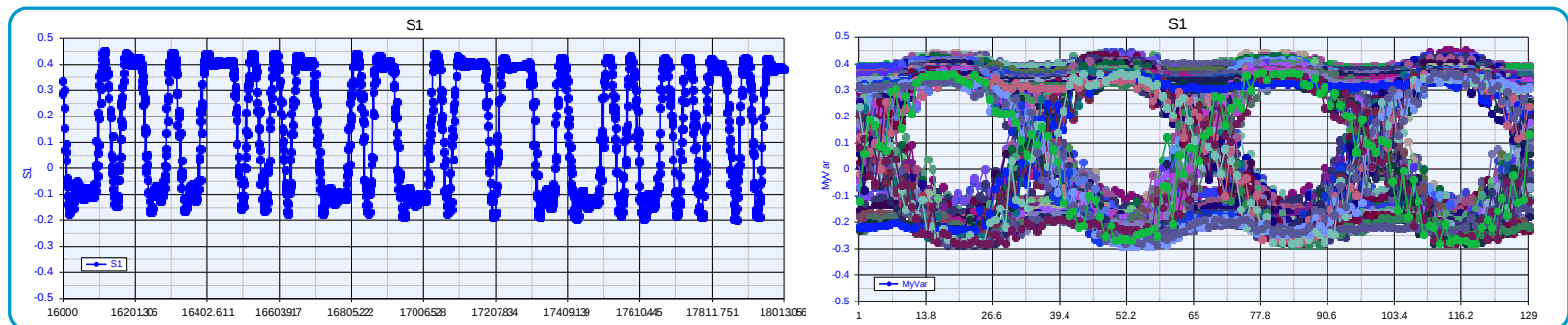
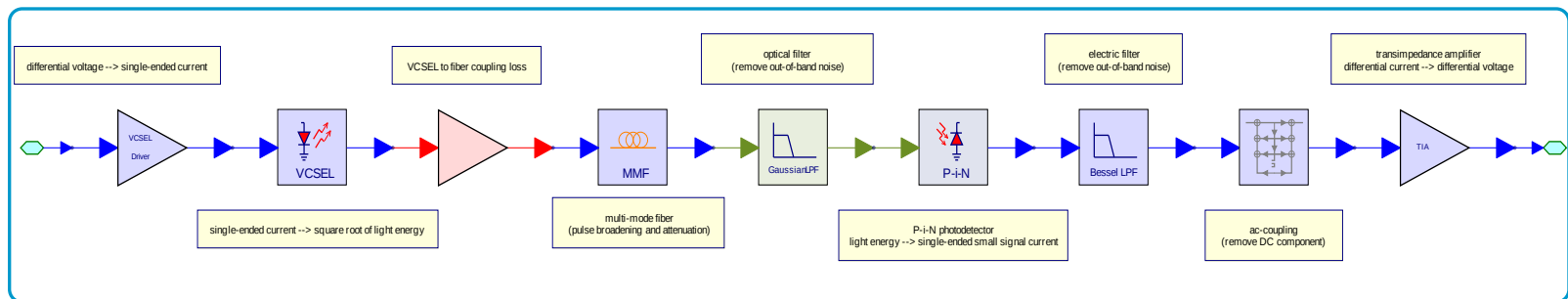


Fig 6



VCSEL Verification

- Case 3 ~ optical link simulation
- 25GHz signal transmission
- A whole optical link: current $\rightarrow$ optical signal $\rightarrow$ current



Thanks



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